

FAST RECOVERY RECTIFIERS

VOLTAGE RANGE: 200 --- 1000 V
CURRENT: 0.5 A

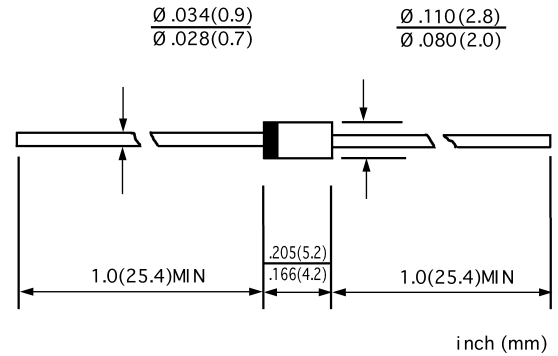
FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Freon Alcohol, Isopropanol and similar solvents

MECHANICAL DATA

- ◇ Case: JEDEC DO--41, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.012 ounces, 0.34 grams
- ◇ Mounting position: Any

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MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 50Hz, resistive or inductive load. For capacitive load, derate by 20%.

		BYD 31D	BYD 31G	BYD 31J	BYD 31K	BYD 31M	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	200	200	600	800	1000	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	0.5					A
Peak forward surge current 10ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	I_{FSM}	15.0					A
Maximum instantaneous forward voltage @ 0.5 A	V_F	1.35					V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	I_R	5.0 100.0					μA
Maximum reverse recovery time (Note1)	t_{rr}	250					ns
Typical junction capacitance (Note2)	C_J	12					pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	55					$^\circ\text{C/W}$
Operating junction temperature range	T_J	-55 ---- + 150					$^\circ\text{C}$
Storage temperature range	T_{STG}	- 55 ---- + 150					$^\circ\text{C}$

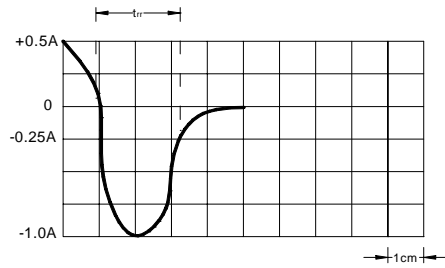
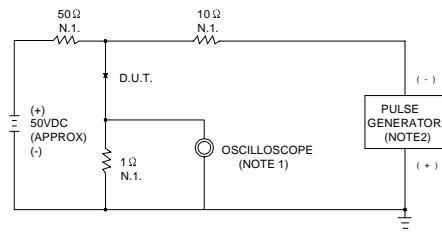
NOTE: 1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{rr}=0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

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FIG.1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = 1MΩ, 22pF
 2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50Ω

SET TIME BASE FOR 50/100 ns / cm

FIG.2 – FORWARD DERATING CURVE

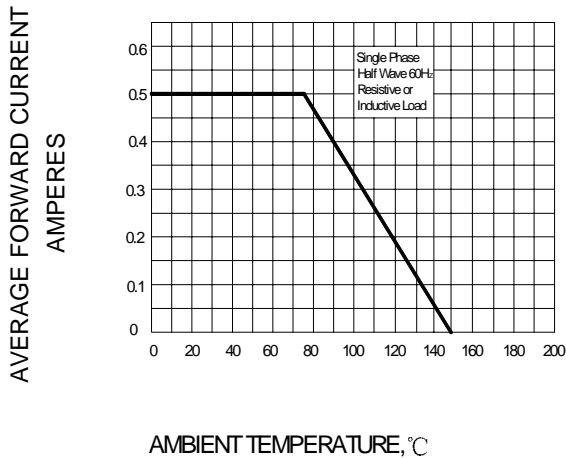


FIG.3 – PEAK FORWARD SURGE CURRENT

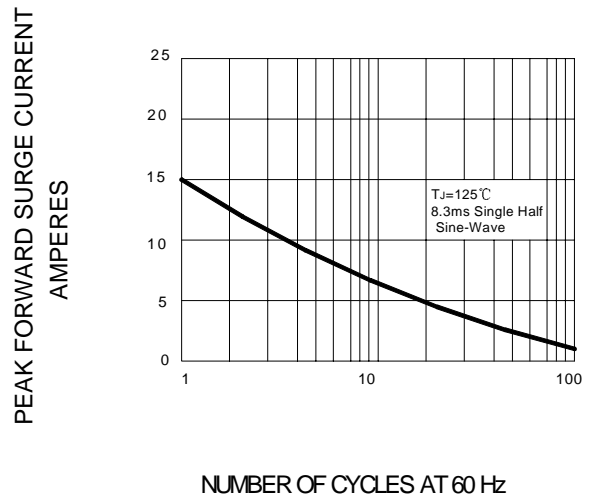


FIG.4 – TYPICAL FORWARD CHARACTERISTIC

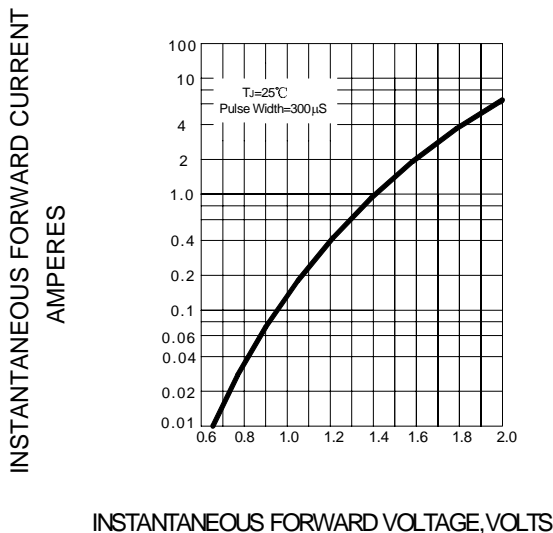


FIG.5 – TYPICAL JUNCTION CAPACITANCE

